

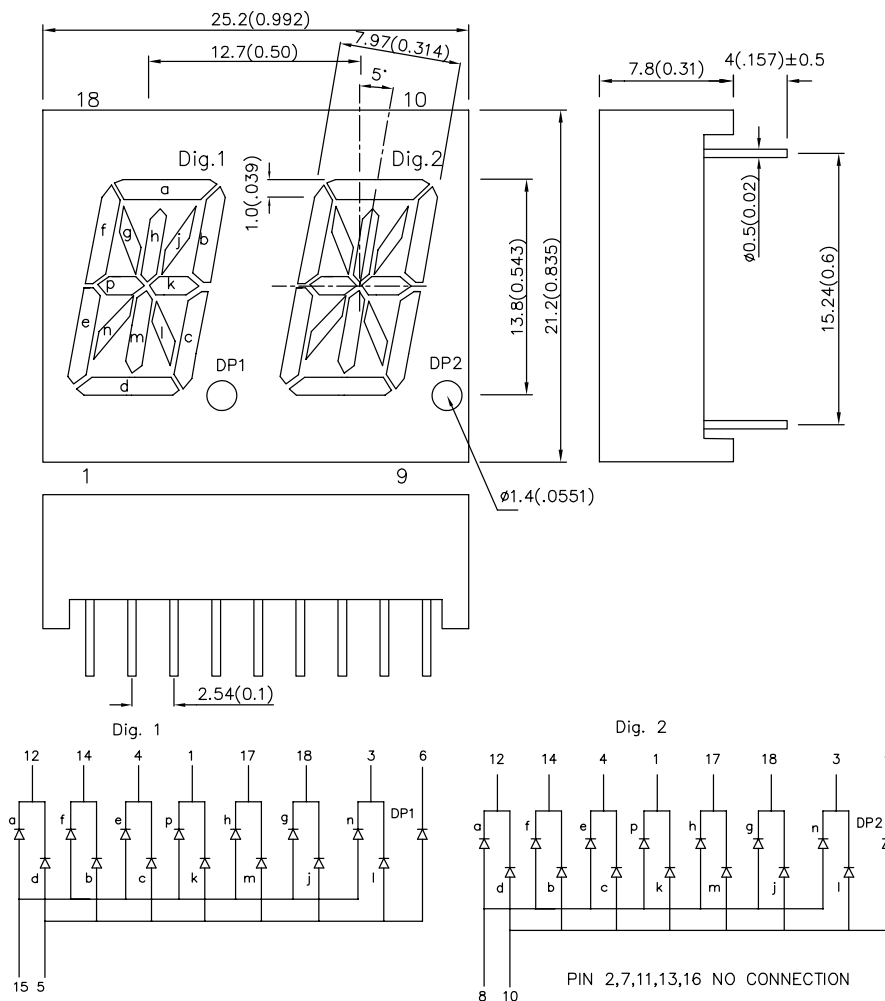
Features

- 0.54 INCH CHARACTER HEIGHT.
- LOW CURRENT OPERATION.
- HIGH CONTRAST AND LIGHT OUTPUT.
- EASY MOUNTING ON P.C. BOARDS OR SOCKETS.
- CATEGORIZED FOR LUMINOUS INTENSITY.
- MECHANICALLY RUGGED.
- STANDARD: GRAY FACE, WHITE SEGMENT.
- RoHS COMPLIANT.

Description

The Super Bright Red source color devices are made with Gallium Aluminum Arsenide Red Light Emitting Diode.

Package Dimensions & Internal Circuit Diagram



Notes:

1. All dimensions are in millimeters (inches), Tolerance is $\pm 0.25 (0.01)$ unless otherwise noted.
2. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Lens Type	Iv (ucd) [1] @ 10mA		Description
			Min.	Typ.	
PDA54-12SRWA	SUPER BRIGHT RED (GaAlAs)	WHITE DIFFUSED	4700	18000	Common Anode, Rt. Hand Decimal.

Note:

1. Luminous Intensity/ Luminous Flux: +/-15%.

Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ_{peak}	Peak Wavelength	Super Bright Red	660		nm	IF=20mA
λ_D [1]	Dominant Wavelength	Super Bright Red	640		nm	IF=20mA
$\Delta\lambda_{1/2}$	Spectral Line Half-width	Super Bright Red	20		nm	IF=20mA
C	Capacitance	Super Bright Red	45		pF	VF=0V;f=1MHz
VF [2]	Forward Voltage Per Segment or DP	Super Bright Red	1.85	2.5	V	IF=20mA
IR	Reverse Current Per Segment or DP	Super Bright Red		10	uA	VR = 5V

Notes:

1. Wavelength: +/-1nm.

2. Forward Voltage: +/-0.1V.

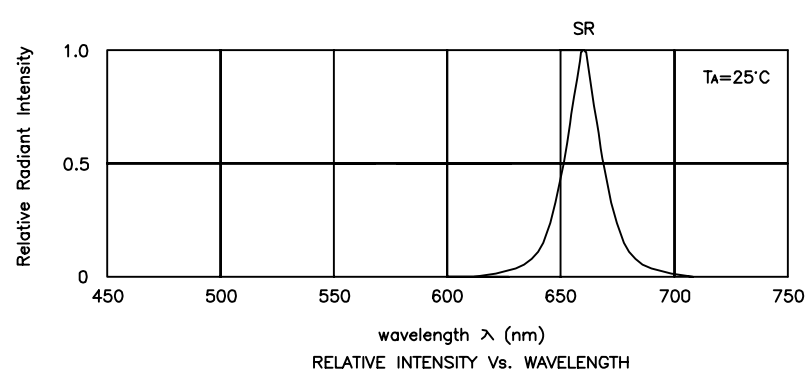
Absolute Maximum Ratings at TA=25°C

Parameter	Super Bright Red	Units
Power dissipation Per Segment or DP	100	mW
DC Forward Current Per Segment or DP	30	mA
Peak Forward Current [1] Per Segment or DP	155	mA
Reverse Voltage Per Segment or DP	5	V
Operating / Storage Temperature	-40°C To +85°C	
Lead Solder Temperature [2]	260°C For 3 Seconds	

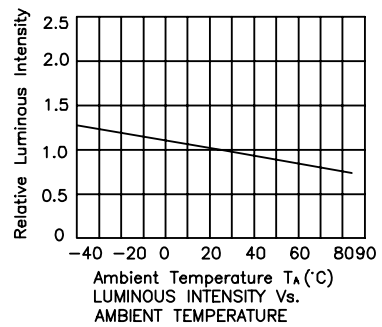
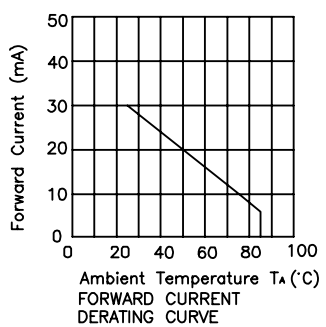
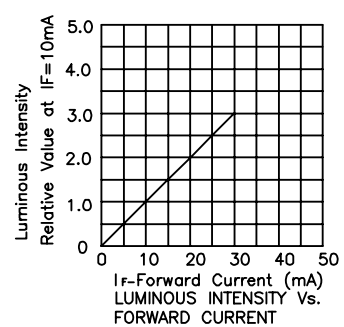
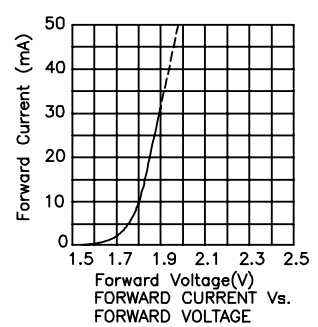
Notes:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.

2. 2mm below package base.



Super Bright Red PDA54-12SRWA



PACKING & LABEL SPECIFICATIONS

PDA54-12SRWA

